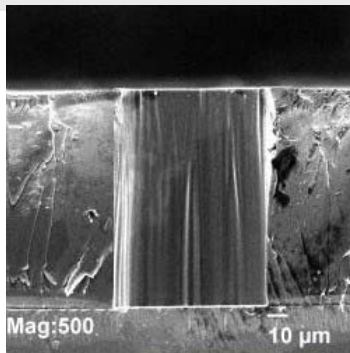


# DuPont™ WB5000™ Series

## DATA SHEET & PROCESSING INFORMATION

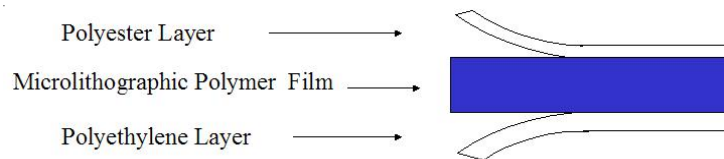
### Microlithographic Polymer Film

High Performance Multi-Purpose Polymer Film for Wafer Bumping Applications



#### MPF PRODUCT FEATURES/ APPLICATION

- Negative working, aqueous processable polymer film
- Three layer package



- Suitable for In-via and mushroom electroplating bumping applications
- Suitable for ENIG and UBM plating
- WB5000™ series is compatible with the following typical surfaces:
  - Silicon
  - Silicon Nitride
  - Sputtered copper
  - Sputtered gold
- WB5000 series exhibits good adhesion to:
  - Glass
  - Polymers
  - Other metals and oxides
- Polymer film thickness
  - 50, 65 microns.
- Unexposed color in Yellow Light
  - Dark Blue/Purple
- Exposed color in Yellow Light
  - Dark Blue

WB5000 is capable of tenting (bridging) over features already etched on the surface. This property is highly dependable on feature size, polymer thickness and lamination conditions.

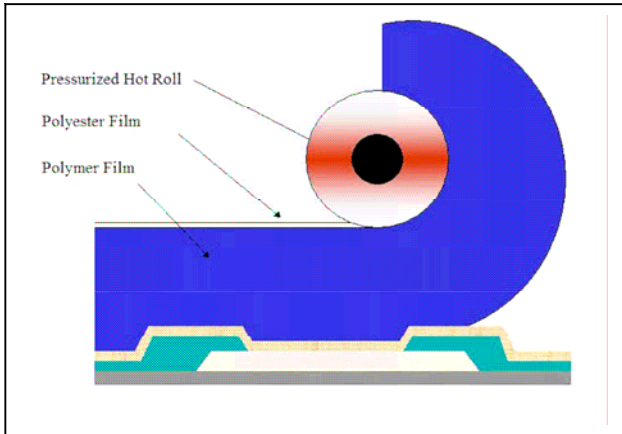


*The miracles of science™*

## PART 1: SURFACE PREPARATION

Surface must be free of any kind of organic contamination and metal oxides from previous processes. It is recommended, whenever possible, to clean the surface with light acid solution (2-3% sulfuric acid solution) followed by D.I. water rinse and dry with nitrogen gas. Cleaning immediately prior to lamination is recommended to remove surface particles and avoid recontamination.

## PART 2: LAMINATION



The main objective of the lamination step is to provide intimate contact between the polymer and the substrate, eliminating any air entrapment, ensuring the polymer flows into the substrate cavities encountered on the surface roughness, maximizing the polymer adhesion.

### HRL Hot Roll Laminator Conditions

- Roll Temperature:
  - 85-110°C (185-230°F); 95°C preferred
- Roll Speed:
  - 0.6-1.5 m/min (2-5 ft/min); 1.2 m/min preferred
- Pressure:
  - 15-40 psig

### Automatic Laminator (Taper)

See equipment manufacturer recommendations.  
Call a DuPont Representative for details

**Note:** Reduced lamination roll pressure and/or temperature may be required if equipment aligned and polymer wrinkles are observed.

**Note:** Substrates must never be stacked horizontally, or random impression defects will be induced.

**Note:** Allow substrates to cool down to room temperature prior to further processing.

## PART 3: POST-LAMINATION HOLD TIME

All photoresists experience some change in photospeed when held over time following lamination. Results differ depending on polymer film type, duration of hold time and the relative humidity (RH) under which the substrates are stored prior to exposure. Low to moderate RH (e.g. 20-50%) has less effect than very high RH (e.g.80-98%).

Do not exceed hold time of 5 days.

## PART 4: POST-LAMINATION BAKE (OPTIONAL)

This optional process step can be used to promote polymer film adhesion. Post lamination bake (PLB) is recommended to enhance film adhesion on extra smooth surfaces and/or for aggressive applications.

### Oven Bake:

Temperature: 55-75°C (122-158°F); 65°C preferred.  
Dwell Time: 15-20 min; 20 min preferred.

### Hot Plate Bake:

Temperature: 90-110°C (194-230°F); 100°C preferred.  
Dwell Time: 10-20 min; 15 min preferred.

**Note:** Temperature will vary according to film thickness, substrate type and process requirements.

## PART 5: EXPOSURE

**Note:** Do not remove polyester coversheet film.

Coversheet has minimum light absorption and provides protection against mask contamination.

**Note:** MPF WB5000 has peak absorption at 365nm, i-line exposure lamps are highly recommended.

**Note:** 20 mW/cm<sup>2</sup> or higher intensity is recommended for high resolution.

### Recommended Exposure Range

	WB5000	WB5050	WB5065
mJ/cm <sup>2</sup>		60 – 200	65 - 220

**Note:** The high end of the recommended exposure range should be used for aggressive applications. All intensity and energy measurements were made at the polymer film surface with an International Light IL-1400A radiometer and an SSD001A Super Slim UV detector probe (275-400 nm sensitivity).

## PART 6: POST-EXPOSURE BAKE (OPTIONAL)

This optional process step, post exposure bake (PEB), is recommended to enhance polymer film resolution and development latitude leading to more complete development and a straighter film sidewall.

### Oven Bake:

Temperature: 70-90°C (158°F); 85°C preferred  
Dwell Time: 20-30 min; 25min preferred

### Hot Plate Bake:

Temperature: 90-110°C (194-230°F); 100°C preferred  
Dwell Time: 20-30 min; 25 min preferred

**Note:** Temperature will vary according to film thickness, substrate type and process requirements.

## PART 7: DEVELOPMENT

**Note:** Remove polyester coversheet film to allow proper development.

### Development Conditions: Recommended for developers with non-stationary spray nozzles

- Spray Pressure: 1.4-2.4 bar (20-35 psig).
- Chemistry: D4000 IC concentrate developer - 0.6-0.9wt%; 0.65 wt% preferred.
- Temperature: 27-32°C (80-90°F); 28°C preferred
- Flow: 180-220 ml/min; 200ml/min preferred
- N<sub>2</sub> Spray: 40 normal m<sup>2</sup>/min
- Rotation Speed: 800 – 1200 rpm; 1000 rpm preferred
- Arm Speed: 200 cycle/min
- Arm Height: 50 mm

### Total development time:

Total Development Time		
	WB5050	WB5065
Time to clean (TTC)	45 - 55 secs	60 – 70 secs
Total development time	85 - 95 secs	110 – 120 secs

Total Development Time @ 28°C (86°F), 2 bar (29 psig) spray pressure, 50% breakpoint @ 0.65% conc.

**Note:** For 200mm and higher wafer diameter development should be set up for 30% of total developing time on the

edges of the wafer only and 70% for the hole wafer surface area.

**Note:** Total developing time will vary slightly with process conditions (exposure dose, baking cycle and hold times). Development should be adjusted by adding 50% to 60% over developing from the clean photoresist breakpoint time.

### Rinsing Recommendations

**Note:** Rinsing should follow immediately after development.

- Rinse water hardness: 150-300 ppm CaCO<sub>3</sub> equivalent. Softer water can be hardened by the addition of magnesium sulfate (Epsom salts).
- Rinse temperature: 21-25°C (70-80°F)
- Rinse spray pressure: 1.4-2.4 bar (20-35 psig).
- Rotation Speed: 800 – 1200 rpm; 1000 rpm preferred
- Arm Speed: 200 cycle/min
- Arm Height: 50 mm
- Develop-to-Rinse Dwell time Ratio: 2:1 minimum.

### Drying Recommendations

**Note:** Drying should follow immediately after rinsing.

- Rotation Speed: 2500-3500 rpm; 3000 rpm preferred
- Arm Height: 80 mm
- Drying N<sub>2</sub> Spray: 40 normal m<sup>2</sup>/min
- Dwell time: 20-40 sec; 30 seconds preferred

**Note:** Minimize white light exposure during post development hold.

## PART 8: POST-DEVELOPMENT BAKE (OPTIONAL)

This optional process step, post development bake (PDB), is the recommended processing latitude leading to straighter film sidewalls and higher resistance to aggressive chemistries.

### Oven Bake:

Temperature: 70-90°C (158°F); 85°C preferred  
Dwell Time: 20-30 min; 25min preferred.

### Hot Plate Bake:

Temperature: 90-110°C (194-230°F); 100°C preferred  
Dwell Time: 20-30 min; 25 min preferred

**Note:** Temperature will vary according to film thickness, substrate type and process requirements.

## PART 9: DESCUM (ASHING)

Plasma etching is recommended to ensure surface is free of any organic contamination and improve surface wet ability for electroplating applications. Please consult equipment manual and manufacturer for details.

## PART 10: PLATING

WB5000 can be used for plating with acid copper, tin/lead, tin. WB5000 has very strong resistance to lifting/underplating and organic leaching. WB5000 maybe used for nickel sulfamate and acid gold baths plating under controlled conditions. Please contact a DuPont technical representative for further details.

## PART 11: REMOVAL

**Note:** Total removal time will vary with process conditions (exposure dose, baking cycle, hold times and etc).

The following removal products have been successfully used:

EKC Technology – EKC 108  
Dynaloy - Dynastrip 7000, 7200, 7500  
General Chemicals - GenSolv 475

Proprietary chemistries are used for higher removal speeds and higher polymer loading. They also minimize chemical attack on surface metallurgy. Operating temperatures are between 50°C and 85°C (125°F and 185°F).

## STORAGE

Temperature: 5-21°C (40-70°F)  
Relative Humidity: 40-60%

## SAFE HANDLING

Note safety and industrial hygiene precautions. Consult the Material Safety Data Sheet (MSDS) of any chemical used. MSDS's for DuPont™ WB Series Microlographic Film are available from your DuPont Representative.

## SAFE LIGHTING

Protect photoresist through lamination and development steps from UV radiation and visible light up to 450 nm by use of gold fluorescent "safe lights".  
High intensity (> 75 foot-candles) yellow "safe light" can cause a change in photospeed over time, and should be avoided.

## WASTE DISPOSAL

For questions concerning disposal of photoresist waste refer to the latest DuPont literature and Federal, State, and Local Regulations.

For more information on DuPont™ WB5000™ Series, please contact your local representative.

DuPont Electronic Technologies  
14 T. W. Alexander Drive  
Research Triangle Park, NC 27709 USA

[www.apl.dupont.com](http://www.apl.dupont.com)

Copyright© 2009 E. I. duPont de Nemours and Company - All rights reserved. This information corresponds to DuPont's current knowledge on the subject. It is offered solely to provide possible suggestions for your own experiments and is not intended to substitute for any testing you may need to conduct to determine the suitability of DuPont's products for your particular purposes. This information may be subject to revision as new knowledge and experience becomes available.

Since DuPont cannot anticipate all variations in actual end-use conditions, it makes no warranties and assumes no liability in connection with any use of this information. Nothing in this publication is to be considered as a license to operate under or a recommendation to infringe any patent right  
Caution : Do not use in medical applications involving permanent implantation in the human body. For other medical applications, see "DuPont Medical Caution Statement", H-51459.



*The miracles of science™*